

SiC SBD P3D06004T2 650V SiC Schottky Diode

Features

- Qualified to AEC-Q101
- Ultra-Fast Switching
- Zero Reverse Recovery Current
- High-Frequency Operation
- Positive Temperature Coefficient on V_F
- High Surge Current
- 100% UIS tested

Benefits

- Improve System Efficiency
- Reduction of Heat Sink Requirement
- Essentially No Switching Losses
- Parallel Devices Without Thermal Runaway

Applications

- Consumer SMPS
- Boost Diodes in PFC or DC/DC Stages
- AC/DC Converters

Order Information

Part Number	Package	Marking
P3D06004T2	TO-220-2	P3D06004T2





Anode 2	Cathode	1
	Anode	2









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1. Maximum Ratings

At T_J= 25°C, unless specified otherwise

Parameter	Symbol	Value	Unit	Test condition
Repetitive Peak Reverse Voltage	V _{RRM}	650	V	T _C = 25℃
Surge Peak Reverse Voltage	V _{RSM}	650	V	T _C = 25℃
DC Blocking Voltage	V _R	650	V	T _c = 25°C
Forward Current	I _F	15 8 4	A	T _c = 25℃ T _c = 125℃ T _c = 160℃
Repetitive Peak Forward Surge Current	I _{FRM}	26 14	А	T _C = 25°C, t _p = 10ms T _C = 125°C, t _p = 10ms
Non-Repetitive Forward Surge Current	I _{FSM}	30 29	А	T _C = 25°C, t _p = 10ms T _C = 125°C, t _p = 10ms
Non-Repetitive Forward Surge Current	I _{F, MAX}	332 337	A	T _C = 25°C, t _p = 10μs T _C = 125°C, t _p = 10μs
Power Dissipation	P _{tot}	81	w	T _C = 25℃
Operating Junction and Storage Temperature	T _J , T _{STG}	-55 to +175	°C	
TO-220 Mounting Torque M3 Screw	T _{orq}	1 8.8	Nm Ibf-in	

2. Thermal Characteristics

Parameter	Symbol	Values	Unit
Thermal Resistance from Junction to Case	R _{θJC}	1.85	°C/W

3. Electrical Characteristics

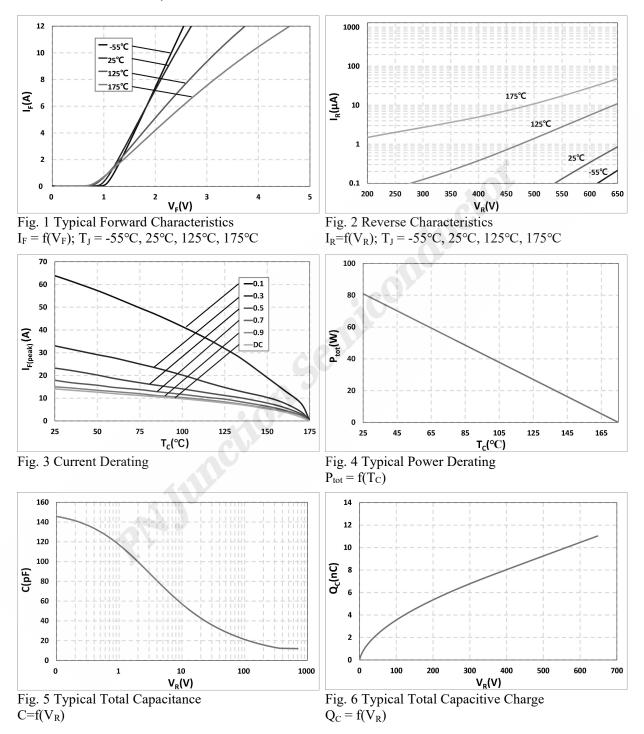
At T_J = 25°C, unless specified otherwise

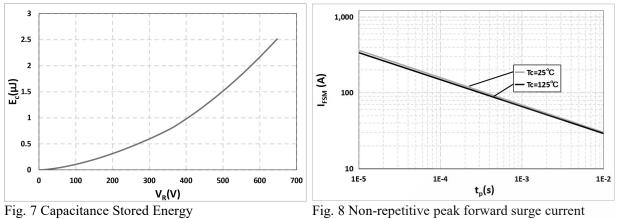
			Values					
Parameter	Symbol	Min.	Тур.	Max.	Unit	Test condition		
Forward Voltage	V _F	1	1.5	1.7	μA	N/	. v	I _F = 4A, T _J = 25℃
	v _F	/	1.8	/		I _F = 4A, T _J = 175℃		
Reverse Current		/	1	20		V _R = 650V, T _J = 25°C		
Reverse current	I _R	/	48			V _R = 650V, T _J = 175°C		
	C		145			V _R = 0V, T _J = 25°C f= 1MHz		
Total Capacitance			15.7	/	pF	V _R = 200V, T _J = 25°C f= 1MHz		
			12.2	-		V _R = 400V, T _J = 25°C f= 1MHz		
Total Capacitive Charge	Q _c	/	8.03	/	nC	V _R = 400V, I _F = 4A T _J = 25°C		
Capacitance Stored Energy	E _C	/	1	/	µJ	V _R = 400V		

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4. Typical Performance

At T_J= 25°C, unless specified otherwise





 $E_C = f(V_R)$

Fig. 8 Non-repetitive peak forward surge current versus pulse duration (sinusoidal waveform)

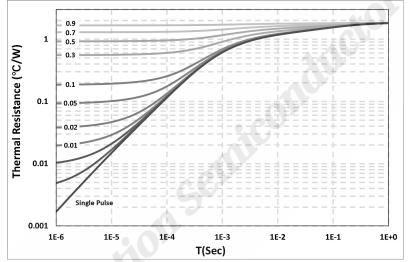
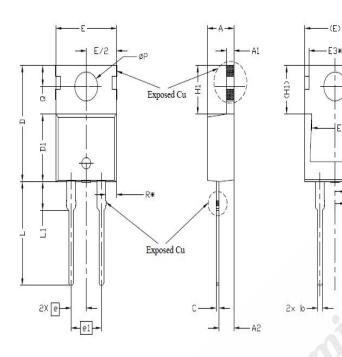


Fig. 9 Transient Thermal Impedance

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5. Package Outlines



		NOTES				
SYMBOL	MIN.	NOM.	MAX.	NOTES		
A	4.24	4.44				
A1	1.15	1.27	1.40			
A2	2.30	2.70				
b	0.70	0.80	0.90			
b1	1.20	1.55	1.75			
b2	1.20	1.45	1.70			
С	0.40	0.50	0.60			
D	14.70	15.37	16.00	4 5 4,5		
D1	8.82	8.92	9.02			
D2	12.63	12.73	12,83 10.36			
E	9.96	10.16				
E1	6.86	7.77	8.89	5		
E3*	8.70REF.					
е		2.54BSC				
e1	e1 5.08BSC					
H1	6.30 6.45		6.60	5,6		
L	13.47	13.72	13.97			
L1	3.60 3.80		4,00	2		
ØP	3.75	3.84	3.93			
Q	2.60	2.80	3.00			
Q1*		1.73REF.				
R*		1.82REF.				

Drawing and Dimensions

Q1*

-2x b2 -2x b1

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